

# Dual N-Channel 20-V (D-S) MOSFET

## **Description**

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low rDS(on) and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

## **Application**

- · DC-DC converters
- · Power management in portable
- Battery-powered products such as computers, Printers
   PCMCIA cards, cellular and cordless telephones.

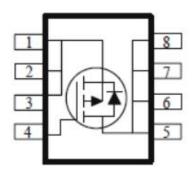
### **Packing & Order Information**

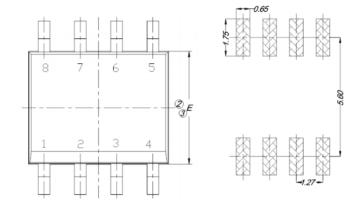
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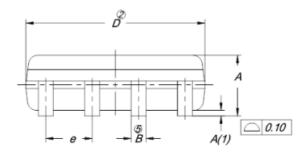


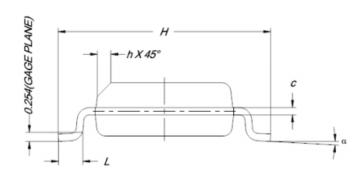
RoHS COMPLIANT

## **Graphic symbol**









DI14	MILLIMETERS			
DIM.	MIN.	NOM.	MAX.	
Α	1.35	1.55	1.75	
A(1)	0.10	0.18	0.25	
В	0.38	0.45	0.51	
С	0.19	0.22	0.25	
D	4.80	4.90	5.00	
E	3.80	3.90	4.00	
е	1.27 BSC			
Н	5.80	6.00	6.20	
L	0.50	0.72	0.93	
α	0°	4°	8°	
h	0.25	0.38	0.50	



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## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (T <sub>A</sub> =25°C unless otherwise noted)					
Symbol	Parameter	Value	Unit		
$V_{DS}$	Drain-Source Voltage	-20	V		
V <sub>GS</sub>	Gate-Source Voltage	±12	V		
I <sub>D</sub>	Drain Current -Continuous (T <sub>A</sub> =25°C)	-8.3	А		
	Drain Current -Continuous (T <sub>A</sub> =70°C)	-6.7	А		
$I_{DM}$	Drain Current Pulsed	±50	А		
Is	Continuous Source Current (Diode Conduction) a	-2.1	А		
$P_D$	Power Dissipation <sup>a</sup> (T <sub>A</sub> =25°C)	3.1	W		
	Power Dissipation <sup>a</sup> (T <sub>A</sub> =70°C)	2.0			
T <sub>J</sub> ,T <sub>STG</sub>	Operating and Storage Temperature Range	-55 to +150	°C		

Thermal Resistance Characteristics				
Symbol	Parameter	Value	Units	
$R_{\theta JA}$	Maximum Junction-to-Ambient <sup>a</sup> ( t<= 10 sec)	40	9000	
	Maximum Junction-to-Ambient <sup>a</sup> (Steady State)	70	°C/W	

### **Notes**

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Static					
Symbol	Test Conditions	Min	Тур.	Max.	Units
$V_{GS(th)}$	$V_{GS} = V_{DS}$ , $I_D = 250uA$	-0.7			V
r DS(on)	$V_{GS} = -4.5 \text{ V}$ , $I_D = -8.3 \text{ A}$ $V_{GS} = -2.5 \text{ V}$ , $I_D = -6.7 \text{ A}$			60 80	mΩ
I <sub>DSS</sub>	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}, Tj = 55^{\circ}\text{C}$			-1 -5	uA
I <sub>GSS</sub>	$V_{GS} = \pm 12 \text{ V}$ , $V_{DS} = 0 \text{ V}$			±100	nA
I <sub>D(on)</sub>	V <sub>GS</sub> = -10 V , V <sub>DS</sub> = -4.5 V	-50			А
V <sub>SD</sub>	V <sub>GS</sub> = 0 V , I <sub>S</sub> = 2.5 A		-0.6		V
Gfs	$V_{DS} = -15 \text{ V}$ , $I_{D} = -8.3 \text{ A}$		70		S



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Dynamic Characteristics					
Symbol	Test Conditions	Min	Тур.	Max.	Units
$t_{d(on)}$			15		ns
t <sub>r</sub>	$V_{DD} = 15 \text{ V}, I_{D} = 1 \text{ A}, R_{L} = 6 \Omega$		10		ns
$t_{d(off)}$	V <sub>GEN</sub> = 10 V		54		ns
tf			26		ns
Q <sub>g</sub>	$V_{DS} = 15 \text{ V}, I_{D} = 10 \text{ A},$ $V_{GS} = 4.5 \text{ V}$		15		nC
$Q_{gs}$			3		nC
$Q_gd$			5		nC

### **Notes**

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.



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